

Non-Synchronous PWM Boost Controller



General Description

The FP5208, FP5208A and FP5208B are boost topology switching regulator for wide operating voltage applications. They provide built-in gate driver pin for driving external N-MOSFET. The non-inverting input of error amplifier connects to a 0.6V precision reference voltage. They have programmable soft start time set by external capacitors. FP5208 and FP5208B have programmable frequency set by external resistors. FP5208A and FP5208B have programmable current detection and over current protection set by external resistors.

The FP5208A and FP5208B are available in the small footprint DFN-12L package to fit in space-saving PCB layout for application fields.

Features

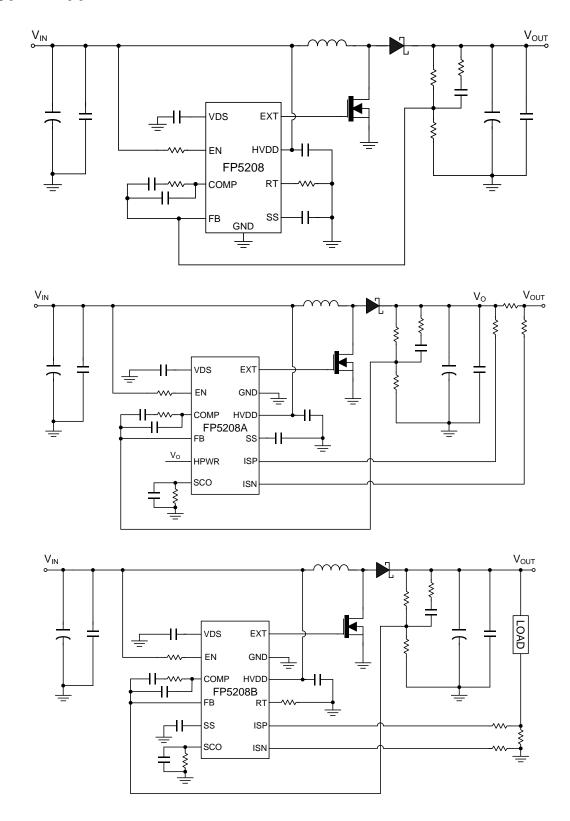
- Wide Supply Voltage Operating Range: 2.5V to 24V
- Precision Feedback Reference Voltage: 0.6V (±2%)
- ➤ Shutdown Current: <1µA
- > Internal Fixed PWM Frequency: 200KHz / FP5208A
- > Programmable PWM Frequency: 100KHz~1000KHz / FP5208, FP5208B
- Programmable Soft Start Function (SS)
- > Light Load Detection / FP5208A, FP5208B
- Programmable Over Current Protection (OCP) / FP5208A, FP5208B
- Over Temperature Protection (OTP)
- > Package: SOP-8L(EP) / FP5208, DFN-12L / FP5208A, FP5208B

Applications

- Chargers
- > LCD Displays
- > Handheld Devices
- Portable Products

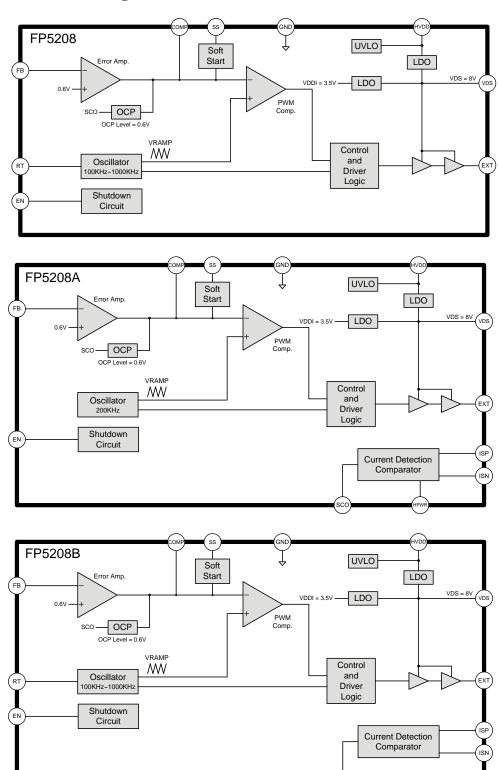


Typical Application Circuit





Function Block Diagram

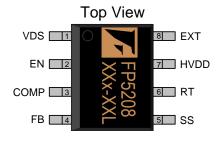


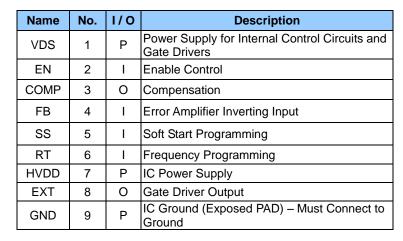
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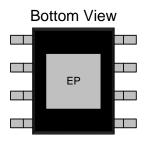


Pin Descriptions

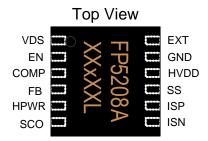
SOP-8L (EP)

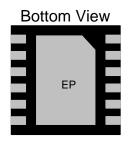






DFN-12L



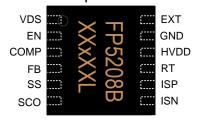


Name	No.	1/0	Description
VDS	1	Р	Power Supply for Internal Control Circuits and Gate Drivers
EN	2	I	Enable Control
COMP	3	0	Compensation
FB	4	I	Error Amplifier Inverting Input
HPWR	5	Р	Current Sense Comparator Power Supply
SCO	6	I	Adjustable Output Current Protection
ISN	7	ı	Current Sense Comparator Inverting Input
ISP	8	ı	Current Sense Comparator Non-inverting Input
SS	9	- 1	Soft Start Programming
HVDD	10	Р	IC Power Supply
GND	11	Р	IC Ground
EXT	12	0	Gate Driver Output
EP	13	Р	Exposed PAD – Connect to Ground

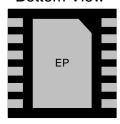


DFN-12L

Top View



Bottom View

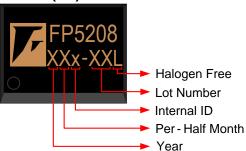


Name	No.	1/0	Description
VDS	1	Р	Power Supply for Internal Control Circuits and Gate Drivers
EN	2	I	Enable Control
COMP	3	0	Compensation
FB	4	I	Error Amplifier Inverting Input
SS	5	I	Soft Start Programming
SCO	6	I	Adjustable Output Current Protection
ISN	7	I	Current Sense Comparator Inverting Input
ISP	8	I	Current Sense Comparator Non-inverting Input
RT	9	I	Frequency Programming
HVDD	10	Р	IC Power Supply
GND	11	Р	IC Ground
EXT	12	0	Gate Driver Output
EP	13	Р	Exposed PAD – Connect to Ground

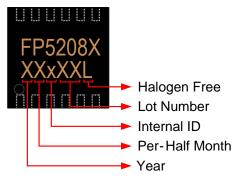


Marking Information

SOP-8L(EP)



DFN-12L



Halogen Free: Halogen free product indicator **Lot Number**: Wafer lot number's last two digits

For Example \rightarrow Lot: 123456 \rightarrow XXx-56L

Internal ID: Internal Identification Code

Per-Half Month: Production period indicator in half month time unit

For Example : $A \rightarrow First Half Month of January$

B → Second Half Month of January
 C → First Half Month of February

D → Second Half Month of February

Year: Production year's last digit



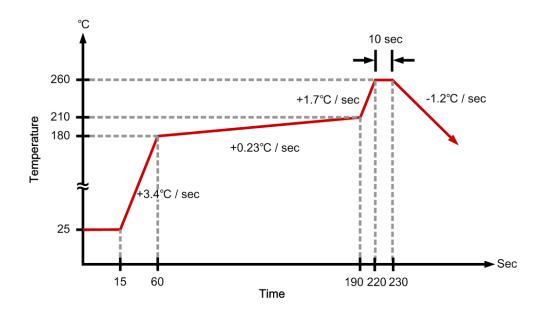
Ordering Information

Part Number	Operating Temperature	Package	MOQ	Description
FP5208XR-G1	-25°C ~ 85°C	SOP-8L (EP)	2500EA	Tape & Reel
FP5208AdR-G1	-25°C ~ 85°C	DFN-12L	2500EA	Tape & Reel
FP5208BdR-G1	-25°C ~ 85°C	DFN-12L	2500EA	Tape & Reel

Absolute Maximum Ratings

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Supply Voltage	HVDD		0		25	V
HPWR, ISP, ISN (FP5208A)			0		25	V
ISP, ISN (FP5208B)			0		6	V
VDS,EXT Voltage			0		16	V
Others Pin Voltage			0		6	V
Thermal Resistance (Junction to Ambient)	θја	SOP-8L (EP)			+60	°C/W
Thermal Resistance (Junction to Ambient)		DFN-12L			+60	°C/W
Thermal Resistance (Junction to Case)	θ _{JC}	SOP-8L (EP)			+10	°C/W
Thermal Resistance (Junction to Case)	OJC	DFN-12L			+10	°C/W
Junction Temperature	TJ				+150	°C
Operating Temperature	T _{OP}		-25		+85	°C
Storage Temperature	T _{ST}		-65		+150	°C
Lead Temperature		(soldering, 10 sec)			+260	°C

IR Re-flow Soldering Curve



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Recommended Operating Conditions

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Supply Voltage	HVDD		2.5		24	V
Operating Temperature Range	T _A	Ambient Temperature	-25		+85	°C

DC Electrical Characteristics (HVDD=12V, T_A=25°C, unless otherwise specified)

		(11VBB=12V, 1A=29 C				
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
System Supply Input						
Input Supply Range	HV_{DD}		2.5		24	V
Under Voltage Lockout	V_{UVLO}			2.2		V
UVLO Hysteresis				0.1		V
Average Current	Icc	FB=0.4V, Switching		1		mA
Quiescent Current	I _{CC}	FB=0.8V, No Switching		245		μΑ
Shutdown Current	Icc	V _{EN} =GND			1	μΑ
Input Supply Voltage	V _{DS}	HV _{DD} =12V, I _{DS} =0A		8		V
Oscillator	•			•	•	
		FP5208A	160	200	240	KHz
Operation Frequency	fosc	RT=NC, FP5208/FP5208B	160	200	240	KHz
		RT=50KΩ,FP5208/FP5208B	400	500	600	KH _Z
Maximum Duty Ratio	%	FB=0.4V		90		%
Soft Start		,				
Soft-Start bias Current	I _{SS}	V _{ss} =0V		1.5		μΑ
Reference Voltage						
Feedback Voltage	V_{FB}	HV _{DD} =12V	0.588	0.6	0.612	V
Enable Control	•					
Enable Voltage	V _{EN}		1.6			٧
Shutdown Voltage	V _{EN}				0.7	٧
External Transistor Connectio	n current					
EXT Pull-UP Resistance	R _{EXTH}	V _{DS} =8V		1		Ω
EXT Pull-Down Resistance	R _{EXTL}	V _{DS} =8V		1		Ω
Current Sense						
		ISP-ISN=1mV RG1=RG2=1K Ω ,R _{SCO} =20K Ω	16	20	24	mV
SCO Voltage	V _{SCO}	ISP-ISN=10mV RG1=RG2=1K Ω ,R _{SCO} =20K Ω	190	200	210	mV
		ISP-ISN=20mV RG1=RG2=1K Ω ,R _{SCO} =20K Ω	380	400	420	mV
SCO Source Current	I _{sco}	V _{SCO} =0V			100	μΑ
Current Limit						
SCO Threshold Voltage	V _{sco}		0.588	0.6	0.612	V
Thermal Shutdown						
Thermal Shutdown Threshold	T _{TS}			+150		°C
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Function Description

Operation

The FP5208, FP5208A and FP5208B are voltage mode boost controllers. They operate with pulse width modulation (PWM). The internal resistive divider provides 0.6V reference for the error amplifier. They change to PSM mode when outputs are light load. They can increase efficiency, but PSM mode also increases output voltage ripple.

Soft Start Function

Soft start time is programmable to connect capacitor between SS pin to ground. After the IC is enabled, the output of error amplifier is clamped by the internal soft-start function, which causes PWM pulse width increasing slowly and thus reducing input surge current during power on. The soft start bias current is 1.5µA.

Oscillator

The oscillator frequency can be set from 100KHz to 1000KHz by connecting a resistance between RT to ground. Acceptable resistance values range from $300K\Omega$ to $20K\Omega$. The frequency is 200KHz when the resistance is unconnected. The relationship between the timing resistance RT and frequency is shown in Figure 1. The oscillator frequency can be calculated using formula below.

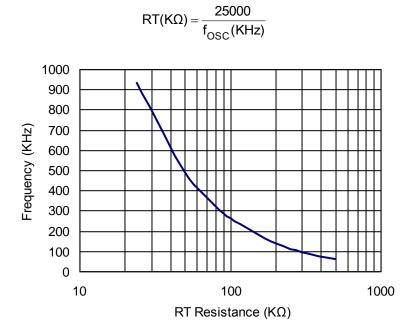


Figure 1. Frequency vs. RT Resistance

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Enable Mode / Shutdown Mode

Drive the EN pin to ground to shutdown the IC. Shutdown mode forces to turn off all internal circuitry, and reduces the HVDD supply current to 1uA (max). The EN pin rising threshold is 1.6V. Before any operation begins, the voltage at EN pin must exceed 1.6V. For automatic startup application, pull up the EN pin with $100k\Omega$ resistance. The EN pin can't be left floating.

Current Detection and Over Current Protection

Figure 2 shows as below the FP5208A current detection and over current application circuit, the load current (I_L) flows R_S and generates a voltage difference V_S . The SCO pin voltage can be calculated using formula below.

$$V_{SCO} = V_S \times \frac{R_{SCO}}{RG1}$$

The over current protection is triggered when the SCO pin voltage is higher than 0.6V, which cause output voltage decreasing. The capacitor is added from SCO pin to ground, which is a simple method to delay the converting time. When a transient voltage happens at sense resistance (R_S), the IC would change sourcing current to the SCO pin and generate a voltage change. The HPWR is power pin of comparator, the voltage must be greater than or equal to ISP pin voltage.

To set the over current trip point, follow below equation:

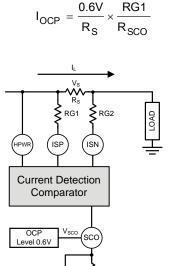


Figure 2. FP5208A Current Detection and Over Current Application Circuit

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Figure 3 shows as below the FP5208B current detection and over current application circuit, the load current (I_L) flows from V_{OUT} to ground and generates a voltage difference V_S at the sense resistance (R_S). The SCO pin voltage can be calculated using formula below.

$$V_{SCO} = V_S \times \frac{R_{SCO}}{RG2}$$

The over current protection is triggered when the SCO pin voltage is higher than 0.6V, which cause output voltage decreasing. The capacitor is added from SCO pin to ground, which is a simple method to delay the converting time. When a transient voltage happens at sense resistance (R_S), the IC would change sourcing current to the SCO pin and generate a voltage change.

To set the over current trip point, follow below equation:

$$I_{OCP} = \frac{0.6V}{R_S} \times \frac{RG2}{R_{SCO}}$$

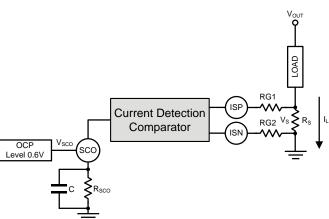


Figure 3. FP5208B Current Detection and Over Current Application Circuit

Thermal Shutdown Protection

The IC will shut down automatically when the internal junction temperature exceeds +150°C. The device can restart until the junction temperature drops below +120°C approximately.

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Application Information

Inductor Selection

Inductance value is decided based on different condition. 4.7µH to 22uH inductance value is recommended for general application circuit. There are three important inductor specifications, DC resistance, saturation current and core loss. Low DC resistance has better power efficiency.

Capacitor Selection

The output capacitor is required to maintain the DC voltage during switching. Low ESR capacitors are preferred to reduce the output voltage ripple. Ceramic capacitor of X5R and X7R are recommended, which have low equivalent series resistance (ESR) and wider operation temperature range.

Diode Selection

Schottky diodes with fast recovery times and low forward voltages are recommended. Ensure the diode average and peak current rating exceed the average output current and peak inductor current. In addition, the diode's reverse breakdown voltage must exceed the output voltage.

Output Voltage Programming

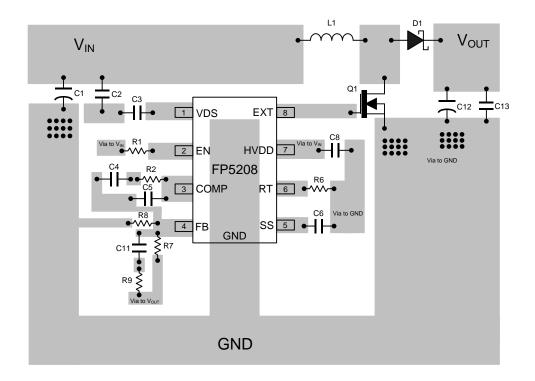
The output voltage is set by a resistive voltage divider from the output voltage to FB. The output voltage is:

$$V_{OUT} = 0.6V \left(1 + \frac{R7}{R8} \right)$$

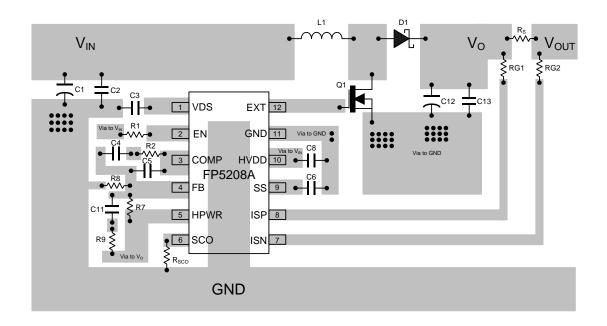


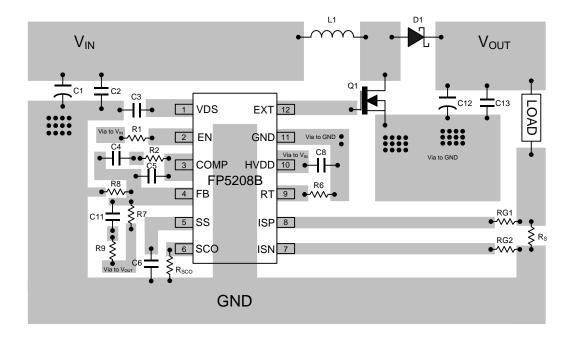
Layout Considerations

- The power traces, consisting of the GND trace, the MOS drain trace and the V_{IN} trace should be kept short, direct and wide.
- 2. Layout switching node MOS drain, inductor and schottky diode connection traces wide and short to reduce EMI.
- 3. Place C8 nearby HVDD pin as closely as possible to maintain input voltage steady and filter noise.
- 4. The resistive divider R7 and R8 must be connected to FB pin directly and as closely as possible.
- 5. FB is a sensitive node. Please keep it away from switching node, MOS drain.
- 6. The GND of the Q1, C1, C2, C12 and C13 should be connected close and together directly to a ground plane.
- 7. RG1 and RG2 must be connected to sense resistance (R_s) directly as closely as possible.
- 8. The output capacitor C12 and C13 should be connected close and together directly to the ground of Q1.









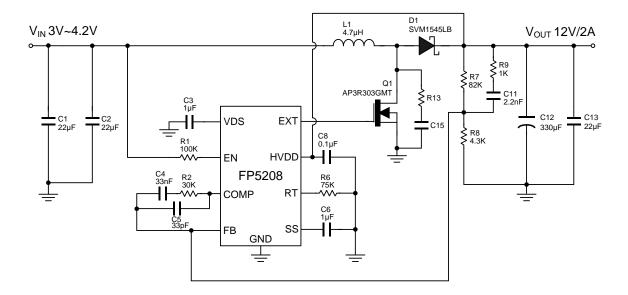
Suggested Layout

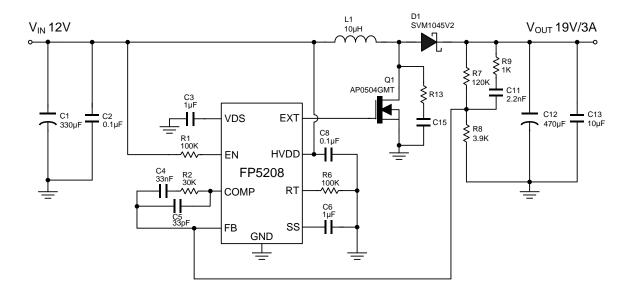
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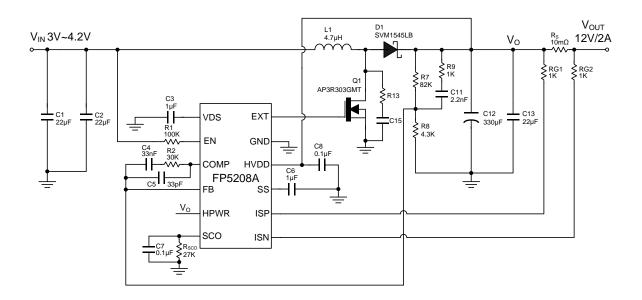
Application Information

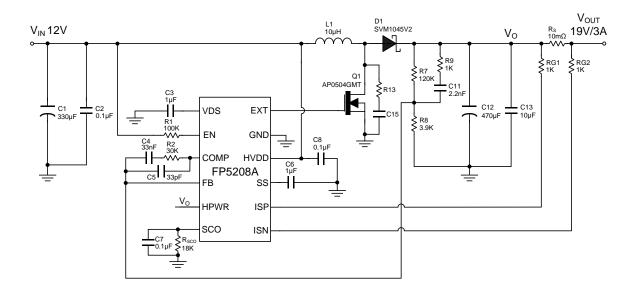




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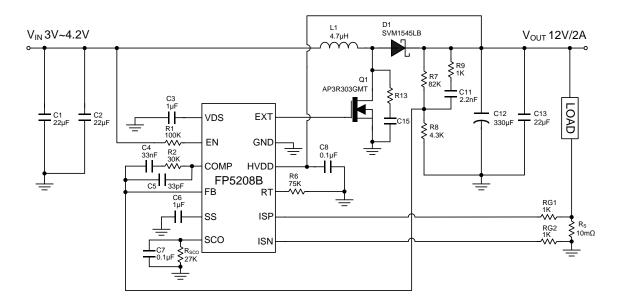


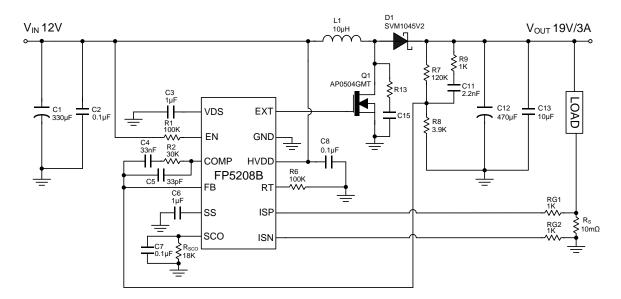




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Note:

- 1. The X5R and X7R of ceramic capacitors are recommended to choose.
- 2. R13 and C15 are added for reducing EMI (Electromagnetic Interference).

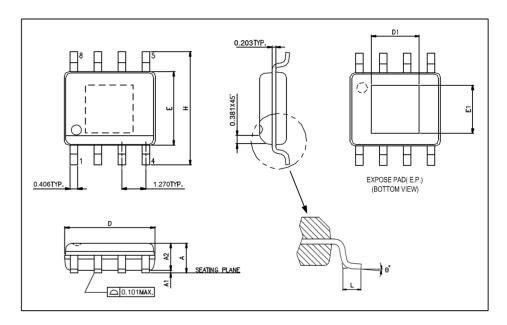
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Package Outline

SOP-8L (EP)



Symbols	Min. (mm)	Max. (mm)
А	1.346	1.752
A1	0.050	0.152
A2		1.498
D	4.800	4.978
Е	3.810	3.987
Н	5.791	6.197
L	0.406	1.270
θ°	0°	8°

Exposed PAD Dimensions:

Symbols	Min. (mm)	Max. (mm)
E1	1.94	2.29
D1	1.94	2.29

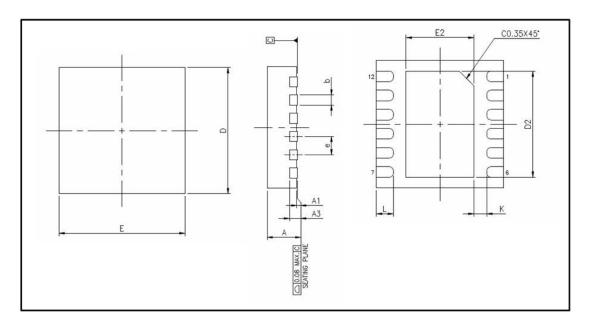
Note:

- 1. Package dimensions are in compliance with JEDEC outline: MS-012 AA.
- 2. Dimension "D" does not include molding flash, protrusions or gate burrs.
- 3. Dimension "E" does not include inter-lead flash or protrusions.

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DFN-12L



Symbols	Min. (mm) Max. (mm)				
А	0.700	0.800			
A1	0.000	0.050			
A3	0.200	REF <u>m</u>			
b	0.180	0.280			
D	3.000	DBSC			
E	3.000BSC				
е	0.450	DBSC			
L	0.300	0.500			
K	0.200	-			

Exposed PAD Dimensions:

Symbols	Min. (mm)	Max. (mm)	LEAD	JEDEC	
Syllibols	Willi. (IIIIII)	wax. (IIIII)	Pure Tin	PPF	CODE
E2	1.500	1.650	V	Х	N/A
D2	2.400	2.550	- V		

Note:

- 1. All dimensions are in millimeters.
- 2. Dimension "b" applies to metalized terminal and is measured between 0.15mm and 0.30mm from the terminal tip. If the terminal has the optional radius on the other end of the terminal, the dimension "b" should not be measured in that radius area.
- 3. Bilateral coplanarity zone applies to the exposed heat sink slug as well as the terminals.

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